## NCE8295AWD

### NCE N-Channel Enhancement Mode Power MOSFET

### **Description**

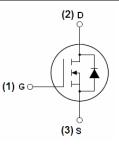
The NCE8295AWD uses advanced trench technology and design to provide excellent  $R_{DS(ON)}$  with low gate charge. This device is suitable for use in PWM, load switching and general purpose applications.

#### **General Features**

- $V_{DS} = 82V, I_D = 95A$  $R_{DS(ON)} < 8.0 \text{ m}\Omega @ V_{GS} = 10V$  (Typ:6.4m $\Omega$ )
- High density cell design for ultra low Rdson
- Fully characterized avalanche voltage and current
- Special designed for convertors and power controls
- Good stability and uniformity with high E<sub>AS</sub>
- Excellent package for good heat dissipation
- Special process technology for high ESD capability

### **Application**

- Power switching application
- Hard switched and High frequency circuits
- Uninterruptible power supply



Schematic diagram



TO-263T-2L top view

100% UIS TESTED! 100% ΔVds TESTED!

### **Package Marking and Ordering Information**

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
NCE8295AWD	NCE8295AWD	TO-263-2L	-	-	-

### Absolute Maximum Ratings (T<sub>A</sub>=25 ℃unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	V <sub>DS</sub>	82	V
Gate-Source Voltage	V <sub>GS</sub>	±20	V
Drain Current-Continuous	I <sub>D</sub>	95	Α
Drain Current-Continuous(T <sub>C</sub> =100 °C)	I <sub>D</sub> (100℃)	67	Α
Pulsed Drain Current	I <sub>DM</sub>	320	Α
Maximum Power Dissipation	P <sub>D</sub>	170	W
Derating factor		1.13	W/℃
Single pulse avalanche energy (Note 5)	E <sub>AS</sub>	529	mJ
Operating Junction and Storage Temperature Range	$T_{J}, T_{STG}$	-55 To 175	$^{\circ}$ C

#### **Thermal Characteristic**

Thermal Resistance, Junction-to-Case (Note 2)	$R_{ heta JC}$	0.88	°C/W

# NCE8295AWD

Electrical Characteristics (T<sub>A</sub>=25°C unless otherwise noted)

Parameter	Symbol	Condition	Min	Тур	Max	Unit
Off Characteristics	•		•	•		
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	V <sub>GS</sub> =0V I <sub>D</sub> =250μA	82	-	-	V
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> =82V,V <sub>GS</sub> =0V	-	-	1	μA
Gate-Body Leakage Current	I <sub>GSS</sub>	$V_{GS}$ =±20V, $V_{DS}$ =0V	-	-	±100	nA
On Characteristics (Note 3)			•			
Gate Threshold Voltage	V <sub>GS(th)</sub>	$V_{DS}=V_{GS},I_{D}=250\mu A$	2	2.9	4	V
Drain-Source On-State Resistance	R <sub>DS(ON)</sub>	V <sub>GS</sub> =10V, I <sub>D</sub> =20A	-	6.4	8.0	mΩ
Forward Transconductance	<b>9</b> FS	V <sub>DS</sub> =5V,I <sub>D</sub> =20A	-	50	-	S
Dynamic Characteristics (Note4)			•			
Input Capacitance	C <sub>lss</sub>	V 051/1/ 01/	-	6800	-	PF
Output Capacitance	Coss	$V_{DS}$ =25V, $V_{GS}$ =0V,	-	353	-	PF
Reverse Transfer Capacitance	C <sub>rss</sub>	F=1.0MHz	-	261	-	PF
Switching Characteristics (Note 4)	•		•	•		
Turn-on Delay Time	t <sub>d(on)</sub>		-	18	-	nS
Turn-on Rise Time	t <sub>r</sub>	VDD=40V,RL=15Ω	-	12	-	nS
Turn-Off Delay Time	$t_{d(off)}$	RG=2.5Ω,VGS=10V	-	56	-	nS
Turn-Off Fall Time	t <sub>f</sub>		-	15	-	nS
Total Gate Charge	Qg	\/ 40\/ L 50A	-	109.3	-	nC
Gate-Source Charge	$Q_{gs}$	V <sub>DS</sub> =40V,I <sub>D</sub> =50A,	-	35.1	-	nC
Gate-Drain Charge	$Q_{gd}$	V <sub>GS</sub> =10V	-	25.8	-	nC
Drain-Source Diode Characteristics	1			JI.		
Diode Forward Voltage (Note 3)	$V_{SD}$	V <sub>GS</sub> =0V,I <sub>S</sub> =95A	-	-	1.2	V
Diode Forward Current (Note 2)	I <sub>S</sub>		-	-	95	Α
Reverse Recovery Time	t <sub>rr</sub>	Tj=25°C,I <sub>F</sub> =100A	-		37	nS
Reverse Recovery Charge	Qrr	di/dt=100A/µs <sup>(Note3)</sup>	-		58	nC

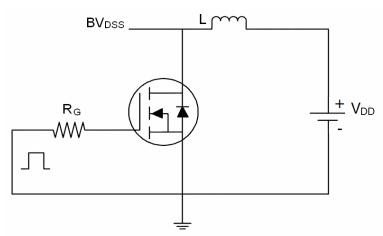
#### Notes:

- 1. Repetitive Rating: Pulse width limited by maximum junction temperature.
- 2. Surface Mounted on FR4 Board, t ≤ 10 sec.
- **3.** Pulse Test: Pulse Width ≤  $300\mu$ s, Duty Cycle ≤ 2%.
- 4. Guaranteed by design, not subject to production
- **5.** EAS condition: Tj=25 $^{\circ}$ C,V<sub>DD</sub>=40V,V<sub>G</sub>=10V,L=0.5mH,Rg=25 $\Omega$

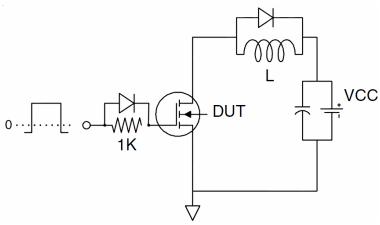


## **Test Circuit**

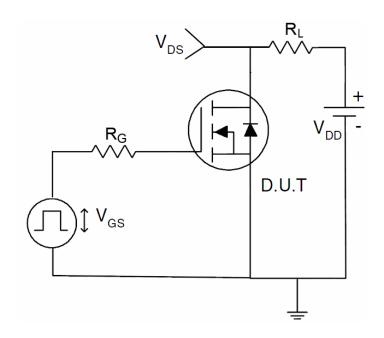
## 1) E<sub>AS</sub> Test Circuits



## 2) Gate Charge Test Circuit

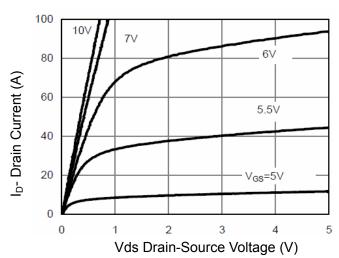


## 3) Switch Time Test Circuit

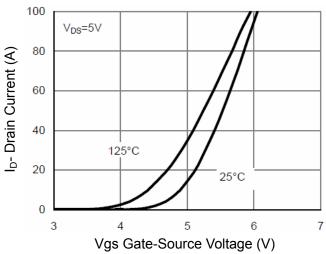




### Typical Electrical and Thermal Characteristics (Curves



**Figure 1 Output Characteristics** 



**Figure 2 Transfer Characteristics** 

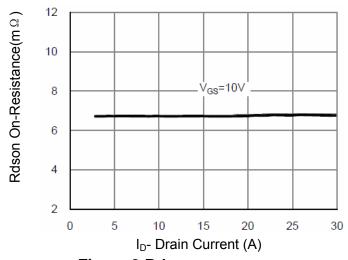
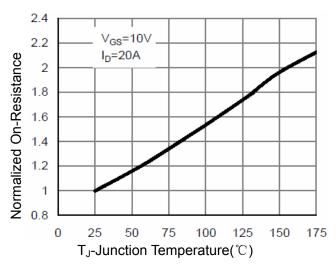


Figure 3 Rdson- Drain Current



**Figure 4 Rdson-Junction Temperature** 

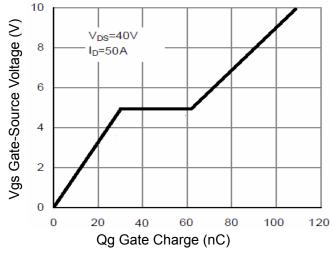


Figure 5 Gate Charge

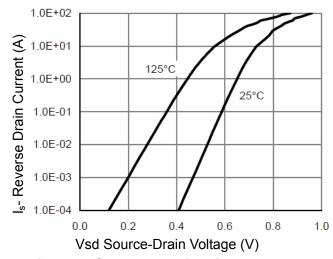


Figure 6 Source- Drain Diode Forward



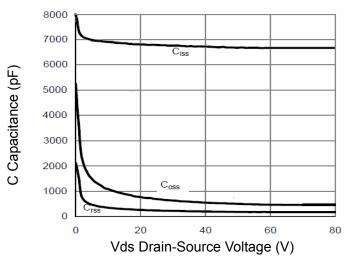


Figure 7 Capacitance vs Vds

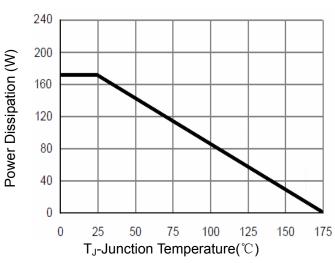
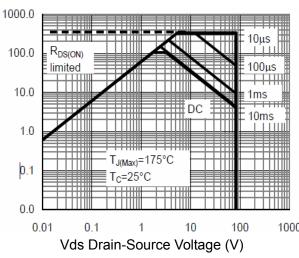


Figure 9 Power De-rating



**Figure 8 Safe Operation Area** 

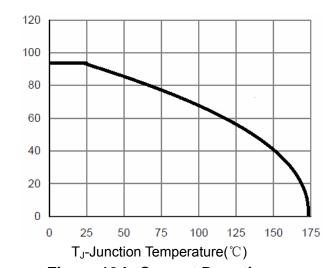
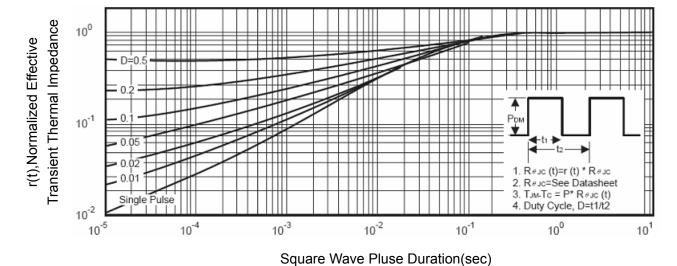


Figure 10 I<sub>D</sub> Current De-rating



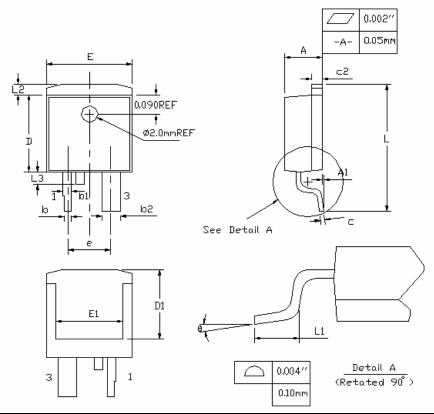
D- Drain Current (A)

Figure 11 Normalized Maximum Transient Thermal Impedance

**Pb Free Product** 



## **TO-263T-2L Package Information**



Comple of	Dimensions	In Millimeters	Dimensions In Inches		
Symbol	Min.	Max.	Min.	Max.	
Α	0.170	0.180	4.32	4.57	
A1	-	0.010	-	0.25	
b	0.028	0.037	0.71	0.94	
b 1	0.035	0.047	0.9	1.2	
b2	0.081	0.095	2.05	2.4	
С	0.018	0.024	0.46	0.61	
c2	0.048	0.055	1.22	1.40	
D	0.350	0.370	8.89	9.40	
D1	0.315	0.324	8.01	8.23	
E	0.395	0.405	10.04	10.28	
E1	0.310	0.318	7.88	8.08	
е	0.200	BSC.	5.08	BSC.	
L	0.580	0.620	14.73	15.75	
L1	0.090	0.110	2.29	2.79	
L2	0.045	0.055	1.15	1.39	
L3	0.050	0.070	1.27	1.77	
θ	0°	8°	0°	8°	



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## NCE8295AWD

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